## PMV48XP



# 20 V, 3.5 A P-channel Trench MOSFET Rev. 1 — 21 December 2010

Product data sheet

## **Product profile**

#### 1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 1.2 Features and benefits

■ Logic-level compatible

Very fast switching

■ Trench MOSFET technology

#### 1.3 Applications

■ High-side loadswitch

Relay driver

■ High-speed line driver

Switching circuits

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>amb</sub> = 25 °C		-	-	-20	V
$V_{GS}$	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	<u>[1]</u>	-	-	-3.5	Α
Static char	racteristics						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; $I_{D}$ = -2.4 A; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.01;$ $T_{j}$ = 25 °C		-	48	55	mΩ

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



## 2. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	1 2	G (F)
			SOT23 (TO-236AB)	017aaa094

## 3. Ordering information

#### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMV48XP	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		

## 4. Marking

#### Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PMV48XP	KN%

[1] % = placeholder for manufacturing site code

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	T <sub>amb</sub> = 25 °C		-	-20	V
$V_{GS}$	gate-source voltage			-12	12	V
$I_D$	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}$	<u>[1]</u>	-	-3.5	Α
		$V_{GS} = -4.5 \text{ V}; T_{amb} = 100 ^{\circ}\text{C}$	<u>[1]</u>	-	-2.2	Α
$I_{DM}$	peak drain current	$T_{amb} = 25 \text{ °C}$ ; single pulse; $t_p \le 10 \text{ µs}$		-	-14	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	510	mW
			<u>[1]</u>	-	930	mW
		T <sub>sp</sub> = 25 °C		-	4150	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode					
Is	source current	T <sub>amb</sub> = 25 °C	<u>[1]</u>	-	-1	Α

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

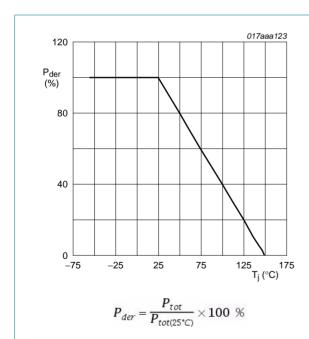


Fig 1. Normalized total power dissipation as a function of junction temperature

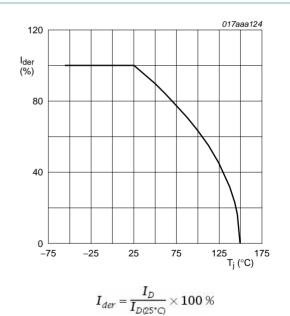
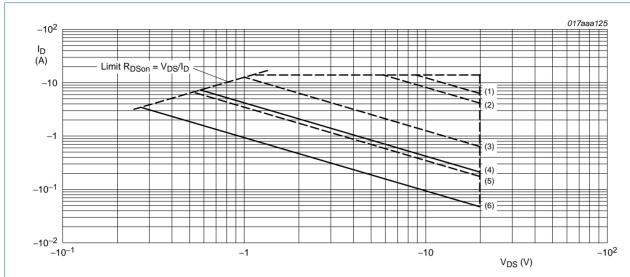


Fig 2. Normalized continuous drain current as a function of junction temperature

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I<sub>DM</sub> = single pulse

- (1)  $t_D = 100 \, \mu s$
- (2)  $t_p = 1 \text{ ms}$
- (3)  $t_p = 10 \text{ ms}$
- (4) DC;  $T_{sp} = 25 \, ^{\circ}\text{C}$
- $(5) t_p = 100 ms$
- (6) DC; T<sub>amb</sub> = 25 °C; drain mounting pad 6 cm<sup>2</sup>

Fig 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

#### 6. Thermal characteristics

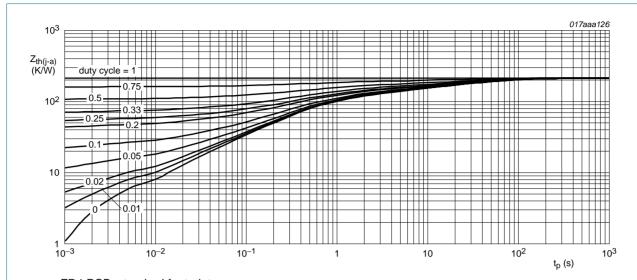
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u>	-	213	245	K/W
			[2]	-	117	135	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	25	30	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

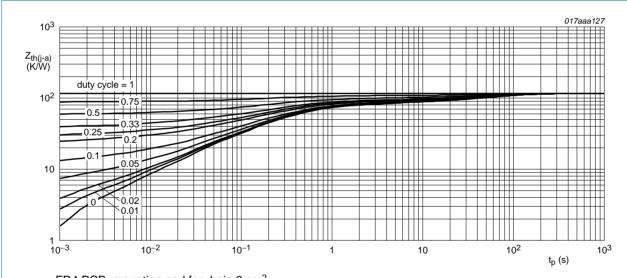
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FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 6 cm<sup>2</sup>

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

## 7. Characteristics

Table 7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-20	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-0.75	-1	-1.25	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_{amb}$ = 25 °C	-	-	-1	μΑ
I <sub>GSS</sub>	gate leakage current	$V_{GS} = -12 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-100	nΑ
20011	drain-source on-state resistance	$V_{GS} = -4.5 \text{ V}; I_D = -2.4 \text{ A}; \text{ pulsed}; $ $t_p \le 300  \mu\text{s}; \delta \le 0.01 ; T_j = 25 ^{\circ}\text{C}$	-	48	55	mΩ
		$V_{GS} = -4.5 \text{ V}; I_D = -2.4 \text{ A}; \text{ pulsed}; $ $t_p \le 300  \mu\text{s}; \delta \le 0.01 ; T_j = 150 ^{\circ}\text{C}$	-	70	80	mΩ
		$V_{GS}$ = -2.5 V; $I_{D}$ = -2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; $\delta \le 0.01$ ; $T_{j}$ = 25 °C	-	71	81	mΩ
9fs	forward transconductance	$V_{DS} = -12 \text{ V}; I_{D} = -2 \text{ A}; \text{ pulsed};$ $t_{p} \le 300  \mu\text{s}; \delta \le 0.01 ; T_{j} = 25 ^{\circ}\text{C}$	-	12	-	S
Dynamic	characteristics					
Q <sub>G(tot)</sub>	total gate charge	$I_D = -1 A$ ; $V_{DS} = -10 V$ ; $V_{GS} = -4.5 V$ ;	-	8.5	11	nC
$Q_{GS}$	gate-source charge	T <sub>j</sub> = 25 °C	-	1.8	-	nC
$Q_{GD}$	gate-drain charge		-	1.8	-	nC
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = -10 \text{ V}; f = 1 \text{ MHz};$	-	1000	-	pF
Coss	output capacitance	T <sub>j</sub> = 25 °C	-	130	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	90	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; $V_{GS}$ = -4.5 V; $R_{G(ext)}$ = 6 $\Omega$ ;	-	11	-	ns
t <sub>r</sub>	rise time	$T_j = 25 ^{\circ}\text{C};  I_D = -1 ^{\circ}\text{A}$	-	13	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	61	-	ns
t <sub>f</sub>	fall time		-	23	-	ns
Source-d	rain diode					
$V_{SD}$	source-drain voltage	$I_S = -2.4 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C};$ $t_p \le 300  \mu\text{s}; \ \delta \le 0.01$	-	-0.82	-1.2	V

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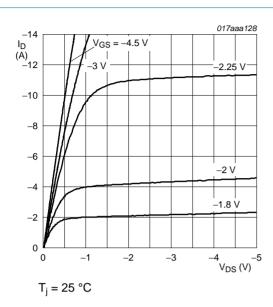
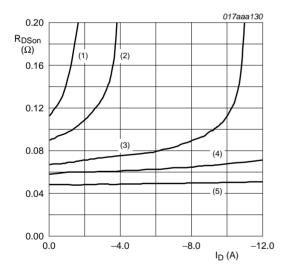


Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values



 $T_i = 25 \, ^{\circ}C$ 

(1)  $V_{GS} = -1.8 \text{ V}$ 

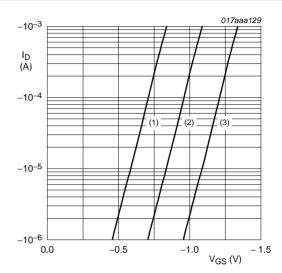
(2)  $V_{GS} = -2.0 \text{ V}$ 

(3)  $V_{GS} = -2.25 \text{ V}$ 

(4)  $V_{GS} = -3.0 \text{ V}$ 

 $(5) V_{GS} = -4.5 V$ 

Fig 8. Drain-source on-state resistance as a function of drain current; typical values



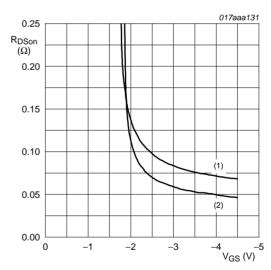
 $T_i = 25 \, ^{\circ}C; \, V_{DS} = -3 \, V$ 

(1) minimum values

(2) typical values

(3) maximum values

Fig 7. Sub-threshold drain current as a function of gate-source voltage

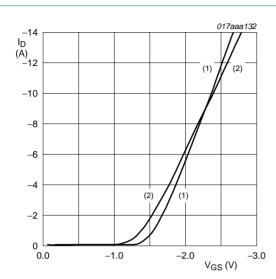


 $I_D = -2.4 \text{ A}$ 

(1)  $T_i = 125 \, ^{\circ}C$ 

(2)  $T_i = 25 \, ^{\circ}C$ 

Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

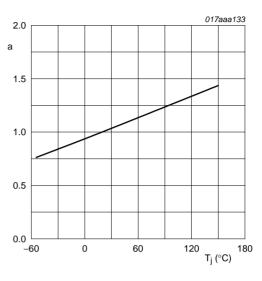


 $V_{DS} > I_D \times R_{DSon}$ 

(1) 
$$T_i = 25 \, ^{\circ}C$$

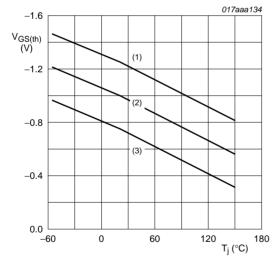
(2) 
$$T_i = 150 \, ^{\circ}\text{C}$$

Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values



$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

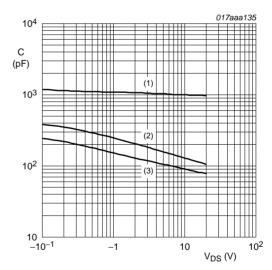
Fig 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values



 $I_D = -0.25 \text{ mA}; V_{DS} = V_{GS}$ 

- (1) maximum values
- (2) typical values
- (3) minimum values

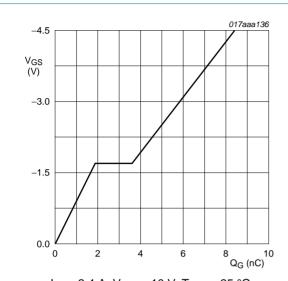
Fig 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

- (1) C<sub>iss</sub>
- (2) Coss
- (3) C<sub>rss</sub>

Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



 $I_D = -2.4 \text{ A}; V_{DS} = -10 \text{ V}; T_{amb} = 25 \text{ °C}$ 

Fig 14. Gate-source voltage as a function of gate charge; typical values

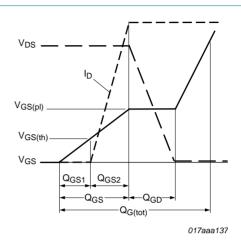
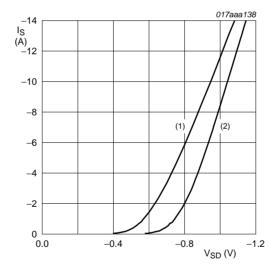


Fig 15. Gate charge waveform definitions



 $V_{GS} = 0 V$ 

(1)  $T_i = 150 \, ^{\circ}\text{C}$ 

(2) T<sub>j</sub> = 25 °C

Fig 16. Source current as a function of source-drain voltage; typical values

## 8. Package outline

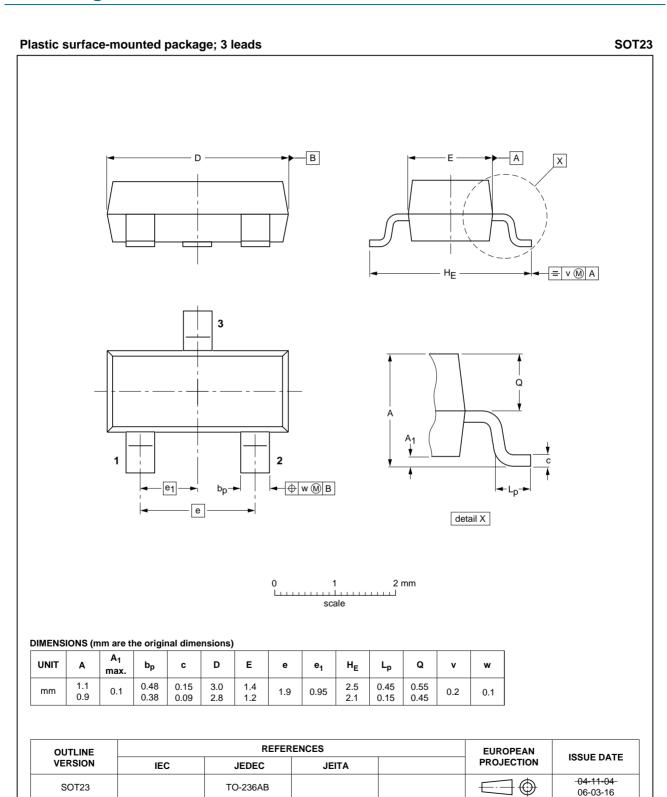
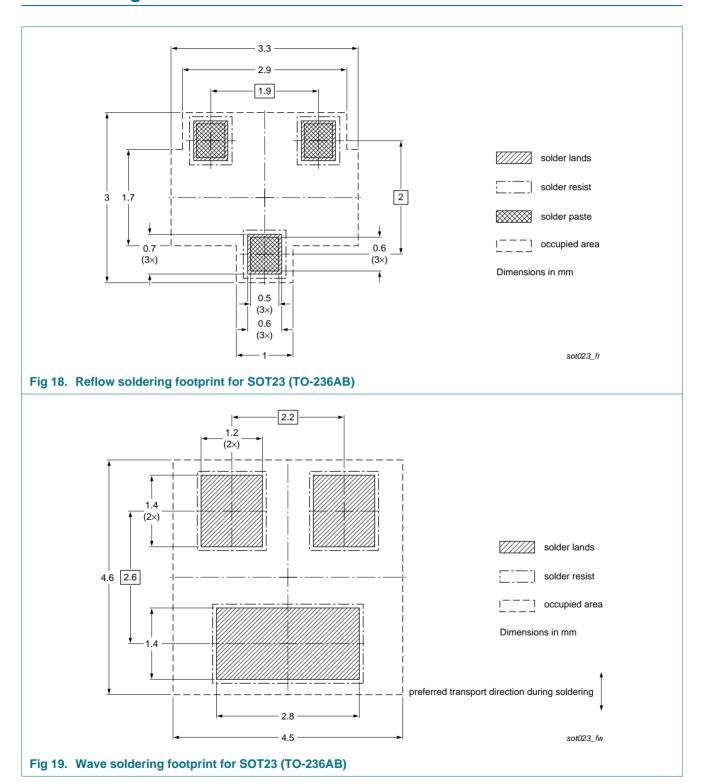


Fig 17. Package outline SOT23 (TO-236AB)

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## 9. Soldering



## 10. Revision history

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMV48XP v.1	20101221	Product data sheet	-	-

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